

MBR30U60CT, MBR30U60FCT, MBR30U60CD

SUPER LOW VF SCHOTTKY RECTIFIERS



VOLTAGE

60Volts

CURRENT

30 Ampers

TO-220AB/ITO-220AB/TO-263

Unit:(mm)

FEATURES

- Power pack
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL Level 1, per J-STD-020, LF MAX peak of 245°C (for TO-263 package)
- Solder bath temperature 275°C maximum, 10s, per JESD22-B106 (for TO-220AB and ITO-220AB package)
- Component in accordance to RoHS 2011/65/EU

MECHANICAL DATA

- Case: JEDEC TO-220AB、ITO-220AB、TO-263
- Molding compound meets UL94V-0 flammability rating
- Terminals: Lead solderable per J-STD-002 and JESD22-B102
- Polarity: As marked
- Mounting Torque: 10 in-lbs maximum

TYPICAL APPLICATIONS

For use in low voltage ,high frequency inverters ,DC/DC converters, free wheeling ,and polarity protection applications

TO-220AB

MBR30U60CT



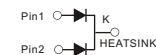
ITO-220AB

MBR30U60FCT



TO-263

MBR30U60CD



Absolute Maximum Ratings

Parameter	Symbol	MBR30U60CT/MBR30U60FCT/MBR30U60CD	Unit
Maximum repetitive peak reverse voltage	V_{RRM}	60	V
Maximum average forward rectified current (see fig.1)	Per leg	15.0	A
	Total device	30.0	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method at rated TL)	I_{FSM}	300	A
Peak repetitive reverse current per diode at $t_p=2\mu s$ 1KHz	I_{RRM}	0.5	A
Operating junction and Storage temperature range	T_J, T_{stg}	-55 to +150	°C
Isolation voltage (ITO-220AB only) from terminals to heatsink $t=1$ min	V_{AC}	1500	V

Electricity Character

Parameter	Test Conditions	Symbol	TYP.	MAX.	Unit
Instaneous forward voltage	Per leg $I_F=15.0A$	$T_A=25^\circ C$	0.51	0.55	V
		$T_A=100^\circ C$	0.48	—	
		$T_A=125^\circ C$	0.46	—	
	Per leg $I_F=5.0A$	$T_A=25^\circ C$	0.38	0.42	
		$T_A=100^\circ C$	0.35	—	
		$T_A=125^\circ C$	0.33	—	
Reverse current	$V_R=60V$	$T_A=25^\circ C$	60	150	μA
		$T_A=100^\circ C$	5	10	mA
		$T_A=125^\circ C$	20	50	
Typical junction capacitance	4V, 1MHz	C_J	570		pF

Notes: 1.Pulse test: 300 μs pulse width, 1% duty cycle

2.Pulse test: pulse width $\leq 40ms$

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RATING AND CHARACTERISTIC CURVES

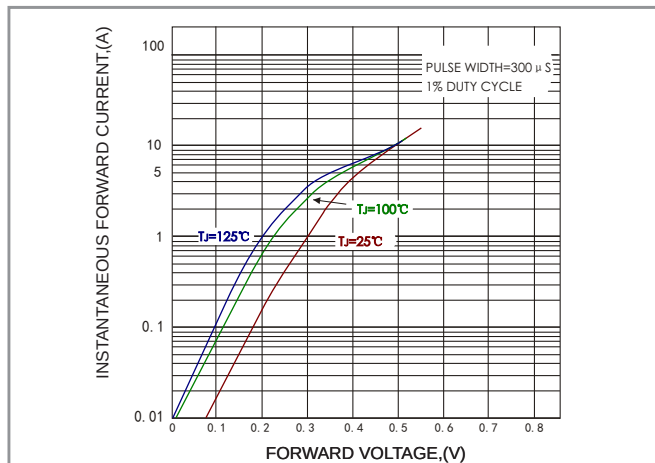


Fig. 1-TYPICAL INSTANTANEOUS FORWARD

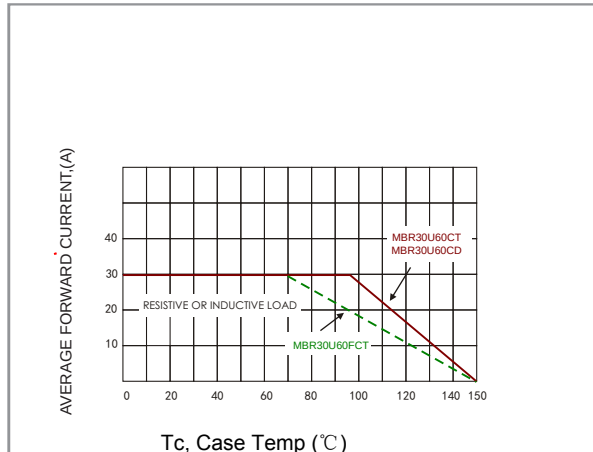


Fig. 2- FORWARD CURRENT DERATING CURVE

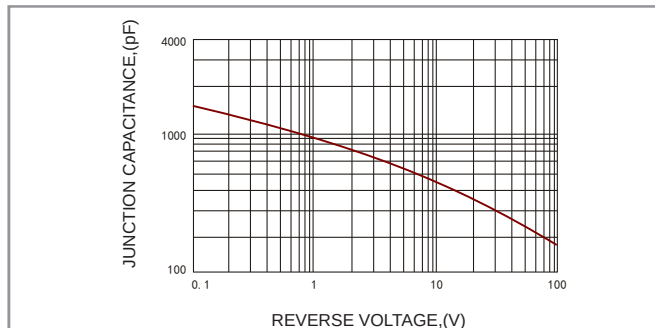


Fig. 3- TYPICAL JUNCTION CAPACITANCE

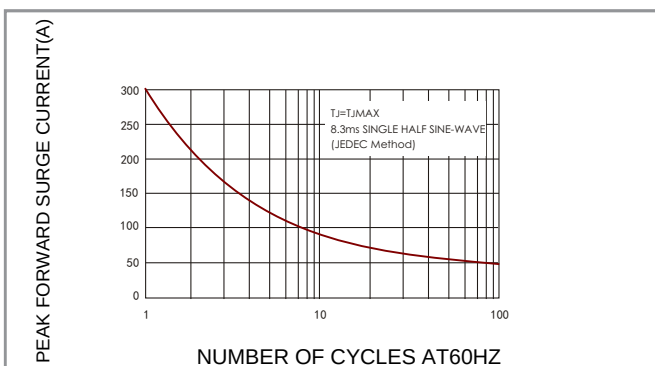


Fig. 5-MAX. NON-REPETITIVE SURGE CURRENT

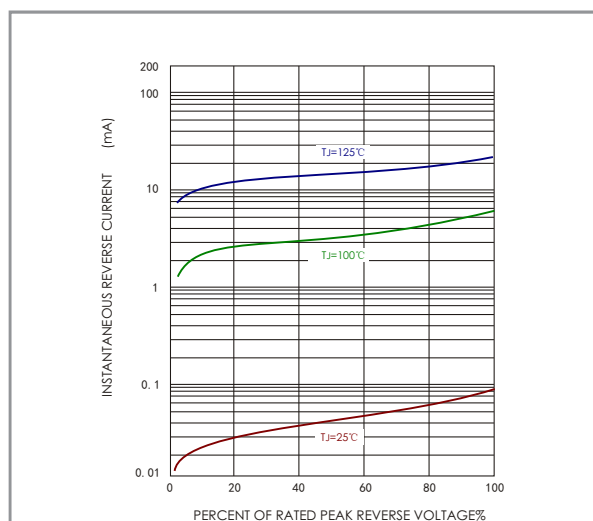


Fig. 4- TYPICAL REVERSE CHARACTERISTICS

Thermal Characteristics (Ratings at 25°C ambient temperature unless otherwise specified)

Parameter	Symbol	MBR30U60CT	MBR30U60FCT	MBR30U60CD	Unit
Typical thermal resistance ³⁾	$R_{\theta jc}$	2.2	4.0	2.2	°C/W

3. Thermal resistance from junction to case

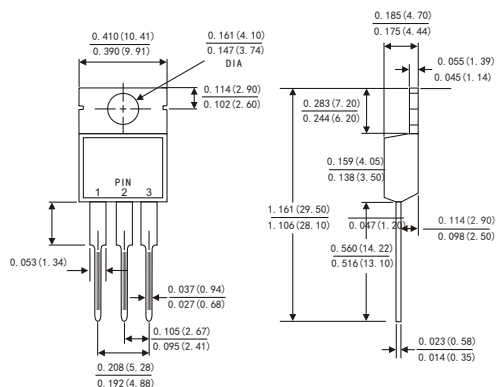
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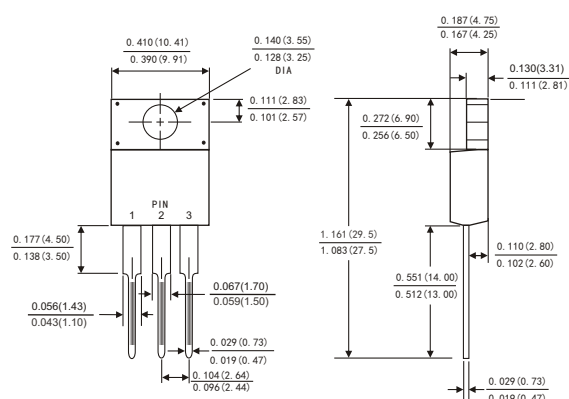


OUTLINE DRAWINGS

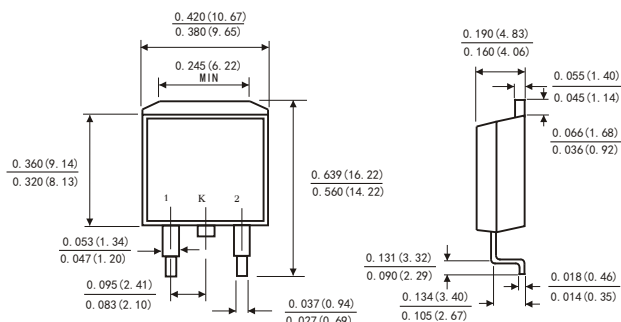
TO-220AB



ITO-220AB

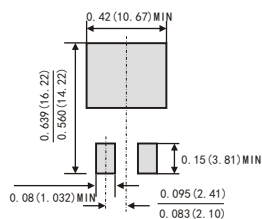


TO-263



Suggested Pad Layout

(TO-263)



ORDER INFORMATION

- Packing information

Product code	Pack	Box Size L×W×H (mm)	Quantity (pcs/box)	Carton Size L×W×H (mm)	Quantity (box/carton)
TO-220AB	P/T	550×150×40	1000	580×230×175	5
ITO-220AB	P/T	550×150×40	1000	580×230×175	5
TO-263	P/T	550×150×40	1000	580×230×175	5

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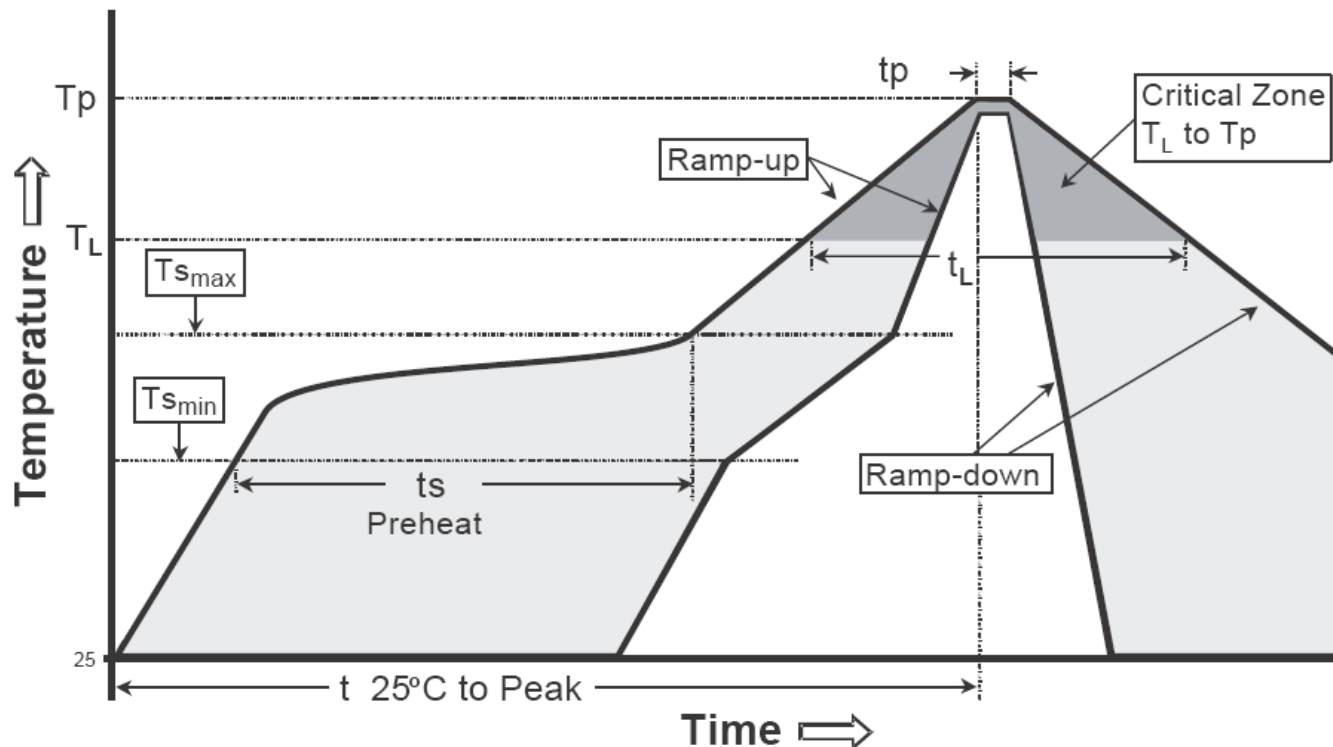
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Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.
Preheat		
-Temperature Min(Ts min)	100°C	150°C
-Temperature Max(Ts max)	150°C	200°C
-Time(ts min to ts max)	60-120 seconds	60-180 seconds
Time maintained above:		
-Temperature (TL)	183°C	217°C
- Time (tL)	60-150 seconds	60-150 seconds
Peak Temperature(TP)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

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